PHY2250 – HW7: Diodes & Power Supplies (Chapter 27)

1.	Trivale	ent means that	the material ha	e material has va		alence electrons.	
		a) Four	b) Three	c) Five	d) Eight		
2.	In a PN junction, the barrier voltage for (doped) silicon is closest to						
		a) 0.3 V	b) 2 V	c) 1 V	d) 0.7 V		
3.	The voltage across an LED is closest to						
		a) 0.3 V	b) 2 V	c) 1 V	d) 0.7 V		
4.	An AC signal with amplitude 4 V is passed through a half-wave rectifier consisting of a silicon diode and a resistor. The peak voltage across the resistor will be						
		a) 3.3 V	b) 4 V	c) 2 V	d) 2.6 V	e) 1.3 V	
5. An AC signal with amplitude 4 V is passed through a bridge-style consisting of a 1:1 transformer, four silicon diodes and a resistor. across the resistor will be							
		a) 3.3 V	b) 4 V	c) 2 V	d) 2.6 V	e) 1.3 V	
6.	An AC signal with amplitude 4 V is passed through a full-wave rectifier consisting of a center-tapped 1:1 transformer, two silicon diodes and a resistor. The peak voltage across the resistor will be						
		a) 3.3 V	b) 4 V	c) 2 V	d) 2.6 V	e) 1.3 V	
7.	The tir	me-average of a	a full-wave rect b) 120 V	tified signal wit c) 240 V	h a peak of 170 d) 85 V	OV is closest to	
8.	Putting it all together: In the diagram below, the V_{source} is 120V, transformer steps down by a factor of 10, the 'diamond' shape is a bridge rectifier, and the capacitor and resistance "very large", what is the (steady-state) DC output voltage?						
				X 4		V _{out}	